

# IS471F

## OPIC Light Detector with Built-in Signal Processing Circuit for Light Modulation System

### Features

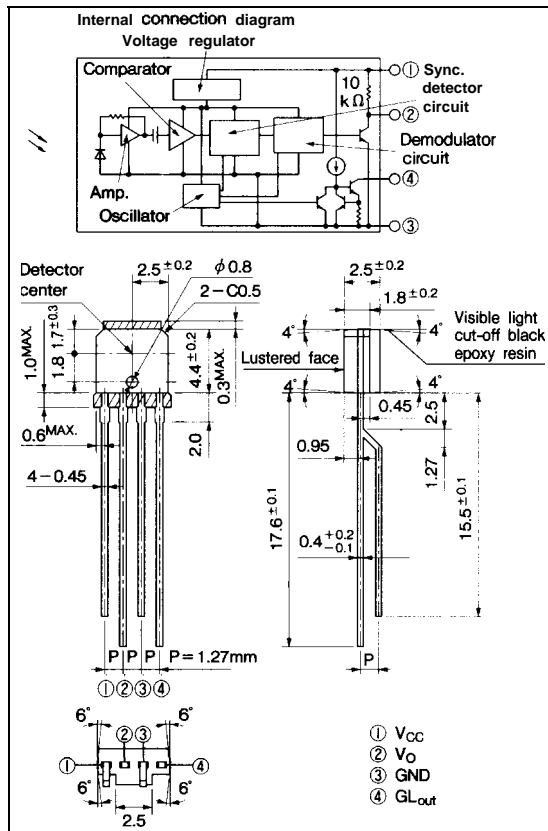
1. Impervious to external disturbing lights due to light modulation system
2. Built-in pulse driver circuit and sync. detector circuit on the emitter side
3. A wide range of operating supply voltage ( $V_{CC}$  :4.5 to 16V)

### Applications

1. Optoelectronic switches
2. Copiers, printers
3. Facsimiles

### Outline Dimensions

(Unit : mm)

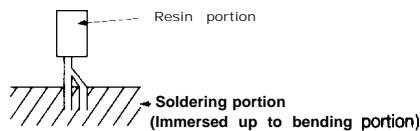


\*"OPIC" (Optical IC) is a trademark of the SHARP corporation  
An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

### Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	-0.5 to 16	v
output	Output voltage	$V_o$	16 v
	Output current	$I_o$	50 mA
*GL output	Output voltage	$V_{GL}$	16 V
Power dissipation	P	250	mW
Operating temperature	$T_{opr}$	-25 to +60	°c
Storage temperature	$T_{stg}$	-40 to +100	°C
*Soldering temperature	$T_{sol}$	260	°C



\*1 Applies to  $GL_{out}$  terminal

\*2 For 5 seconds at the position shown in the right figure

■ Electro-optical Characteristics

(V<sub>CC</sub>=5V, T<sub>a</sub>=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating supply voltage	V <sub>CC</sub>		4.5	—	16	v
Supply current	I <sub>CC</sub>	V <sub>O</sub> , GL <sub>out</sub> terminals shall be opened.	—	3.5	7.0	mA
output	Low level output voltage	V <sub>OL</sub> I <sub>OL</sub> =16mA, E <sub>VP</sub> =500lx, E <sub>VD</sub> =0* <sup>3</sup>	—	0.15	0.35	v
	High level output voltage	V <sub>OH</sub> E <sub>VD</sub> =E <sub>VP</sub> =0* <sup>3</sup>	4.97	—	—	v
	Output short circuit current	I <sub>OS</sub> E <sub>VP</sub> =E <sub>VD</sub> =0* <sup>3</sup>	0.25	0.5	1.0	mA
GL output	Low level output current	I <sub>GL</sub> V <sub>GL</sub> =1.2V	40	55	70	mA
	* <sup>4</sup> Pulse cycle	t <sub>p</sub>	70	130	220	μs
	* <sup>4</sup> Pulse width	t <sub>w</sub>	4.4	8	13.7	μs
* <sup>5</sup> “Low→High” threshold irradiance	E <sub>ePLH</sub>	E <sub>eD</sub> =0* <sup>3</sup> Light emitting diode (λ <sub>p</sub> =940nm)* <sup>6</sup>	—	0.4	2.66	μW/mm <sup>2</sup>
* <sup>5</sup> “High→Low” threshold irradiance	E <sub>ePHL</sub>		—	0.7	2.8	μW/mm <sup>2</sup>
Hysteresis	E <sub>ePLH</sub> /E <sub>ePHL</sub>		0.45	0.65	0.95	—
Response time	High→Low propagation delay time	t <sub>PHL</sub> * <sup>6</sup>	—	400	670	μs
	Low→High propagation delay time	t <sub>PLH</sub> * <sup>6</sup>	—	400	670	μs
* <sup>7</sup> External disturbing light illuminance	E <sub>VDX</sub>	E <sub>ep</sub> =7.5 μW/mm <sup>2</sup> , * <sup>3</sup> λ <sub>p</sub> =940nm	2000	4500	—	lx

\*<sup>3</sup>E<sub>eP</sub> represents illuminance of signal light in sync with the low level timing of output at GL<sub>out</sub> terminal.

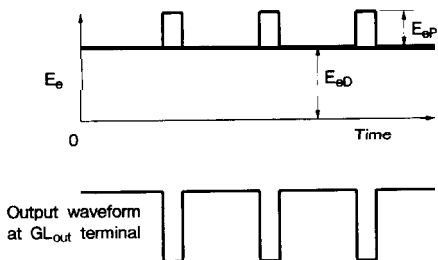
E<sub>eD</sub> represents illuminance of DC light. For detail, see Fig. 1.

Light source : Infrared light emitting diode (λ<sub>p</sub>=940nm)

E<sub>VP</sub> represents illuminance of signal light in sync with the low level timing of output at GL<sub>out</sub> terminal.

E<sub>VD</sub> represents illuminance of DC light. Note that the light source is CIE standard light source A.

Fig.1



(Note) Fig. 1 shows the output waveform at GL<sub>out</sub> terminal with IS471 F connected as shown in Fig. 3.

\*<sup>4</sup>Pulse cycle (t<sub>p</sub>), pulse width (t<sub>w</sub>) are defined as shown in Fig. 2.

The waveform shown in Fig. 2 is the output voltage waveform at GL<sub>out</sub> terminal with IS471 F connected as shown in Fig. 3

Fig.2

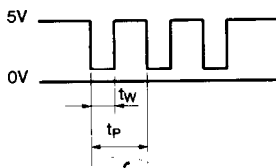
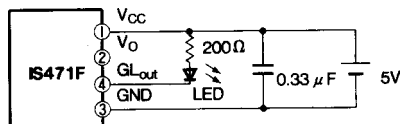


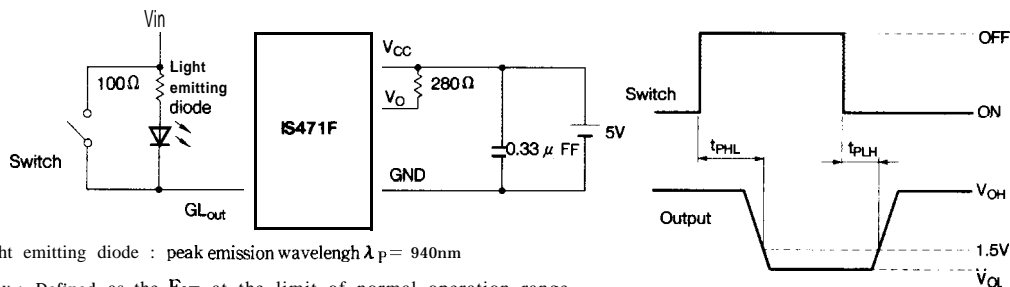
Fig.3



\*<sup>5</sup>Defined as E<sub>eP</sub> that causes the output to go “Low to High” (or “High to Low”)

\*6 Test circuit for response time, threshold irradiance is shown in Fig. 4.

Fig. 4



Light emitting diode : peak emission wavelength  $\lambda_p = 940\text{nm}$

\*7 Evox : Defined as the  $E_{VD}$  at the limit of normal operation range.

Fig. 5 Power Dissipation vs. Ambient Temperature

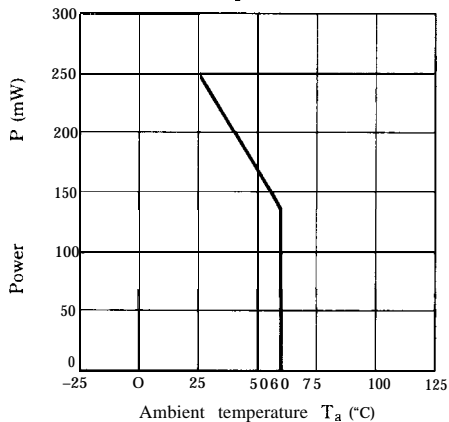


Fig. 6 Low Level Output Voltage vs. Low Level Output Current

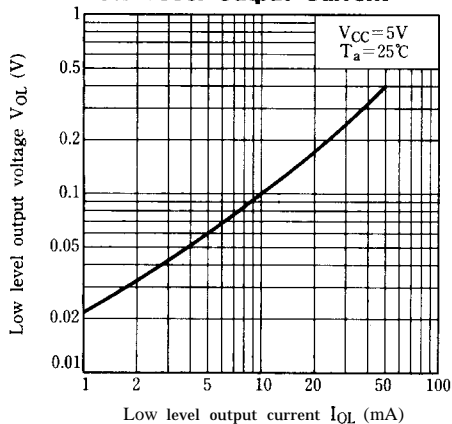


Fig. 7 Low Level Output Voltage vs. Ambient Temperature

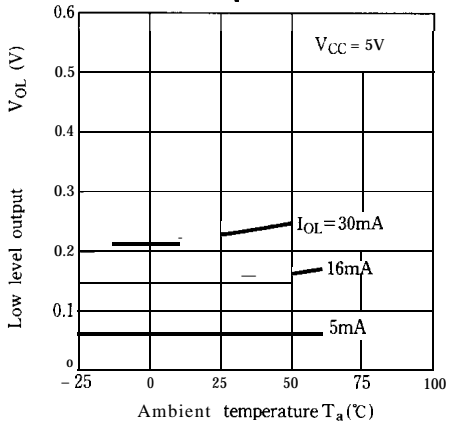
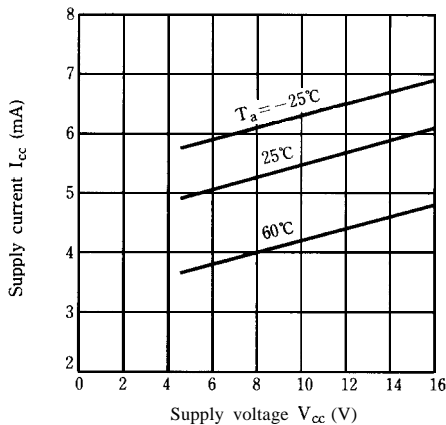
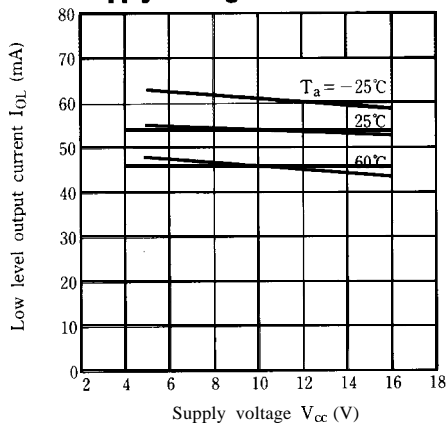


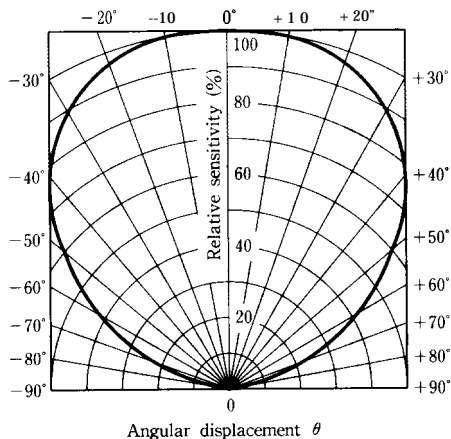
Fig. 8 Supply Current vs. Supply Voltage



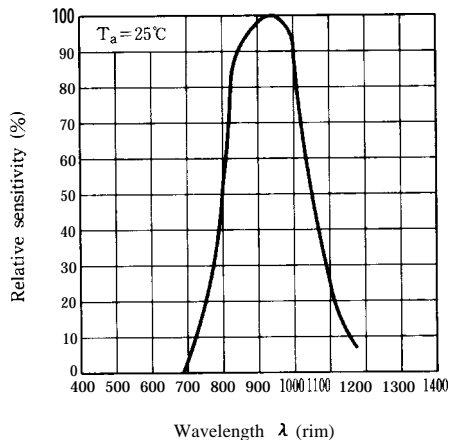
**Fig. 9 Low Level Output Current vs. Supply Voltage**



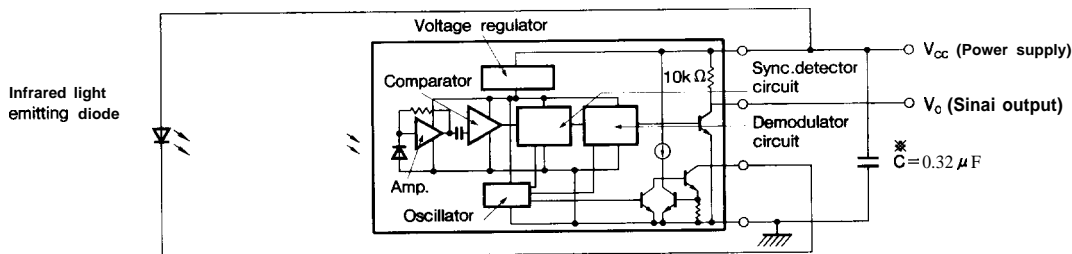
**Fig.10 Sensitivity Diagram ( $T_a=25^\circ\text{C}$ )**



**Fig.11 Spectral Sensitivity**



Basic \*\*



\* In order to stabilize power supply line, connect a by-pass capacitor of  $0.33 \mu\text{F}$  or more between  $V_{cc}$  and GNP near the device.

Please refer to the chapter "Precautions for Use." (Page 78 to 93)